C30739ECERH Series Short Wavelength Enhanced Silicon Avalanche Photodiode



The C30739ECERH large area silicon avalanche photodiode (APD) is intended for use in a wide variety of broadband low light level applications covering the spectral range from below 400 to over 700nm.

The device is designed to have enhanced short wavelength responsivity with quantum efficiency typically exceeding 80% at 430nm. In addition, this large area APD is optimized for low noise and low capacitance (60pF). Operation at an avalanche gain of up to M = 400 at 430nm is feasible with a special high gain version.

The standard ceramic carrier package allows for easy handling and coupling to scintillating crystals such as LSO and BGO. Combined with the superior short wavelength responsivity, it makes this APD ideal in demanding high volume applications such as Positron Emission Tomography (PET).

While the devices are warranted over the entire specification, customers are welcome to discuss their custom requirements to accommodate special design, packaging or testing needs.

Key Features

- Large area silicon APD
- Short Wavelength enhanced responsivity
- High quantum efficiency (80%) at short wavelength(430nm)
- Easy coupling to scintillating crystals
- Non-magnetic package
- Custom packaging available
- Excellent timing resolution
- RoHS compliant

Applications

- Molecular imaging (PET)
- Nuclear medicine
- Fluorescence detection
- High energy physics
- Safety radiation detection
- Optical tomography
- Environmental monitoring



Table 1 – Package and Chip Dimensions

Parameter	Measurement	Unit		
Package Size	8.50 x 8.00 x 1.55	mm		
Chip size	6.65 x 6.65	mm		
Active area	5.6 x 5.6	mm		

Table 2 – Electrical Characteristics, at T_A = 22 °C; at typical dV

Symbol	Parameter	C30739ECERH (standard version)			C30739ECERH-2 (high gain version)					
		Min	Тур	Max	Min	Тур	Max	Unit	Conditions	
V _{op}	Operating Voltage	-	400	420	-	400	450	V		
dV	dV = V _{br} - V _{op}	-	15	-	-	10	-	V	defines relation of operating voltage V _{op} to breakdown voltage V _{br}	
М	Gain at V _{op}	80	100	-	180	200	-			
Q.E.	Quantum Efficiency	65	80	-	65	80	-	%	at 430 nm	
R	Responsivity	-	26	-	-	52	-	A/W	at 430 nm and Typical Gain M	
T_{coeff}	Temp. Coefficient for constant gain		1.2			1.2		V/°C		
CJ	Capacitance	-	60	-	-	60	-	рF	at V _{op}	
t _R	Rise Time	-	2	-	-	2	-	ns		
Ι _D	Dark Current	-	1.5	-	-	2	-	nA	at V _{op}	
I _N	Noise Current	-	0.3	-	-	0.4	-	pA/√Hz	at V _{op}	

Table 3 – Maximum ratings

Parameter	Min	Typical	Max	Unit
Operating Temperature	0	-	50	°C
Storage Temperature	-20	-	70	°C
Maximum Humidity (non-condensing)	-	-	60	%

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Figure 1

Capacitance vs. operating voltage

Figure 2 Spectral Response vs. Wavelength



Electrical properties vs. bias voltage

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Figure 4 Package Dimensions in mm

RoHS Compliance

The C30739ECERH Si APD is designed and built to be fully compliant with the European Union Directive 2011/65/EU – Restriction of the use of certain Hazardous Substances (RoHS) in Electrical and Electronic equipment.



Warranty

A standard 12-month warranty following shipment applies.

About Excelitas Technologies

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Excelitas has a long and rich history of serving our OEM customer base with optoelectronic sensors and modules for more than 45 years beginning with PerkinElmer, EG&G, and RCA. The constant throughout has been our innovation and commitment to delivering the highest quality solutions to our customers worldwide.

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